

**ECE571: Advanced Microprocessor Design – Homework 7**  
Fall 2019

**Due: Thursday 31 October 2019, 2:00pm**

Create a document that contains the data and answers described in the sections below. A .pdf or .txt file is preferred but I can accept MS Office or Libreoffice format if necessary.

**1. TLB Behavior on the Haswell-EP Machine**

For this section, log into the Haswell-EP machine just like in previous homeworks.

- (a) Run `perf list` on the Haswell-EP machine.  
How many TLB-related events are there in the “cache” and “virtual memory” sections? (Hint, in “less” (the pager used by `perf list`) you can use the / (slash) character to start a text search).
- (b) Run the traditional naive matrix-matrix code.

The core loop is listed below.

The default size is 1024, which means a total of three arrays \* 1024 \* 1024 \* 8 bytes (a 64-bit double) or roughly 24MB of memory.

```
/* Matrix multiply */
for(i=0;i<size;i++) {
    for(j=0;j<size;j++) {
        for(k=0;k<size;k++) {
            c[(i*size)+j]+=a[(i*size)+k]*b[(k*size)+j];
        }
    }
}
```

Measure the STL values; the “STLB” is the second-level TLB which is 1024 entries on a Haswell machine.

```
perf stat -e mem_uops_retired.stlb_miss_loads,\
mem_uops_retired.stlb_miss_stores,\
page-faults,major-faults,minor-faults \
/opt/ece571/matrix_multiply/matrix_multiply
```

Report the STL misses caused by stores and loads, as well as the pagefault types (major and minor).

- (c) Now run the swapped (worse) version where the “i” and “j” loops are switched so instead of walking linearly through memory the array access skip around with a stride of 8\*size (8kB).

```
perf stat -e mem_uops_retired.stlb_miss_loads,\
mem_uops_retired.stlb_miss_stores,\
page-faults,major-faults,minor-faults \
/opt/ece571/matrix_multiply/matrix_multiply_swapped
```

Report the STL misses caused by stores and loads, as well as the pagefault types (major and minor).

(d) Answer the following questions:

- i. Did the number of TLB misses go up after switching the access order?
- ii. Did the page faults go up? Why or why not?
- iii. How many TLB entries would be needed to cover 24MB of memory when using 4kb pages?

## 2. Determining TLB Size experimentally

(a) Let's see if we can notice the L1 DTLB size in Haswell-EP, which is 64 entries. This means 256k (262,144 bytes).

Run the following tool which does a linear walk of memory and takes memory size as a parameter. Try 240000, 250000, 260000, 270000, and 280000 bytes. Is there a jump in runtime when the 256k boundary is crossed?

```
perf stat -e mem_uops_retired.stlb_miss_loads,\
mem_uops_retired.stlb_miss_stores,\
page-faults,major-faults,minor-faults \
/opt/ece571/matrix_multiply/memory_walk 240000
```

(b) Try the same experiment but see if you can notice the 1024 page (STLB) boundary at 4MB (4,194,304 bytes). Try 4186112, 4190208, 4194304, 4198400. Did you notice a bump in runtime? Why might there not be one?

There might not be a good answer here. I tried both turning off the prefetcher and using random (rather than linear) accesses without any change in behavior.

Random doesn't show it.

## 3. Read Memory Paper

- There aren't any questions on this, but if you want some advance reading on DRAM that we will be covering you can read this paper: *A Performance & Power Comparison of Modern High-Speed DRAM Architectures* by Li, Reddy, and Jacob.  
<https://user.eng.umd.edu/~blj/papers/memsys2018-dramsim.pdf>

## 4. Submitting your work

- Create the document containing the data as well as answers to the questions asked.
- Please make sure your name appears in the document.
- e-mail the file to me by the homework deadline.